

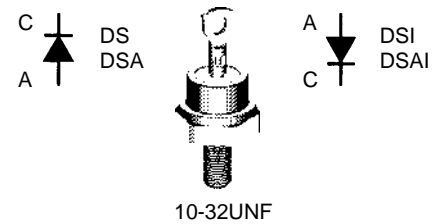
Rectifier Diode Avalanche Diode

$V_{RRM} = 800-1800 \text{ V}$
 $I_{F(RMS)} = 40 \text{ A}$
 $I_{F(AV)M} = 25 \text{ A}$

V_{RSM} V	$V_{(BR)min}$ ① V	V_{RRM} V	Anode on stud	Cathode on stud
900	-	800	DS 17-08A	DSI 17-08A
1300	-	1200	DS 17-12A	DSI 17-12A
1300	1300	1200	DSA 17-12A	DSAI 17-12A
1700	1750	1600	DSA 17-16A	DSAI 17-16A
1900	1950	1800	DSA 17-18A	DSAI 17-18A

① Only for Avalanche Diodes

DO-203 AA



A = Anode C = Cathode

Symbol	Test Conditions	Maximum Ratings	
$I_{F(RMS)}$	$T_{VJ} = T_{VJM}$	40	A
$I_{F(AV)M}$	$T_{case} = 125^{\circ}\text{C}; 180^{\circ}$ sine	25	A
P_{RSM}	DSA(I) types, $T_{VJ} = T_{VJM}, t_p = 10 \mu\text{s}$	7	kW
I_{FSM}	$T_{VJ} = 45^{\circ}\text{C}; V_R = 0$	t = 10 ms (50 Hz), sine t = 8.3 ms (60 Hz), sine	370 A 400 A
	$T_{VJ} = T_{VJM}; V_R = 0$	t = 10 ms (50 Hz), sine t = 8.3 ms (60 Hz), sine	300 A 320 A
I^2t	$T_{VJ} = 45^{\circ}\text{C}; V_R = 0$	t = 10 ms (50 Hz), sine t = 8.3 ms (60 Hz), sine	680 A ² s 660 A ² s
	$T_{VJ} = T_{VJM}; V_R = 0$	t = 10 ms (50 Hz), sine t = 8.3 ms (60 Hz), sine	450 A ² s 430 A ² s
T_{VJ}		-40...+180	°C
T_{VJM}		180	°C
T_{stg}		-40...+180	°C
M_d	Mounting torque	2.2-2.8	Nm
		19-25	lb.in.
Weight		6	g

Features

- International standard package, JEDEC DO-203 AA (DO-4)
- Planar glassivated chips

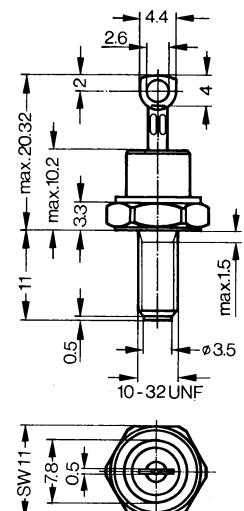
Applications

- Supplies for DC power equipment
- DC supply for PWM inverter
- Field supply for DC motors
- Battery DC power supplies

Advantages

- Space and weight savings
- Simple mounting
- Improved temperature and power cycling
- Reduced protection circuits

Dimensions in mm (1 mm = 0.0394")



Data according to IEC 60747

IXYS reserves the right to change limits, test conditions and dimensions

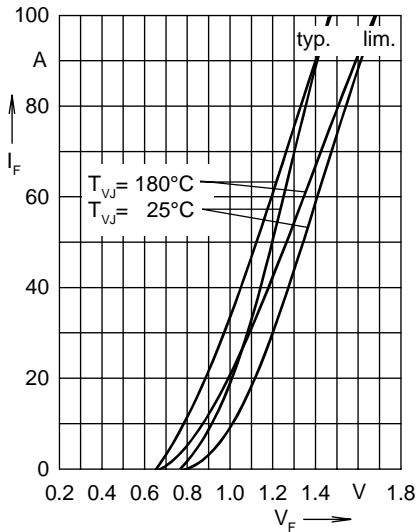


Fig. 1 Forward characteristics

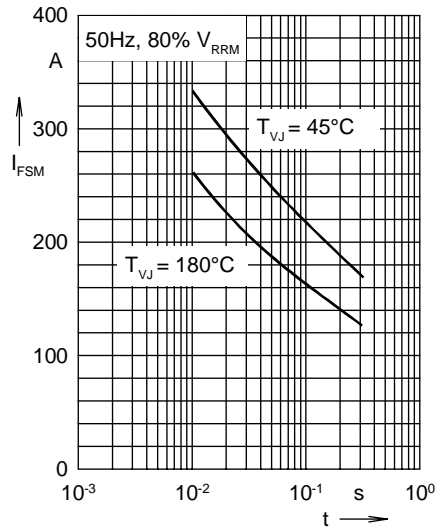


Fig. 2 Surge overload current
 I_{FSM} : crest value, t: duration

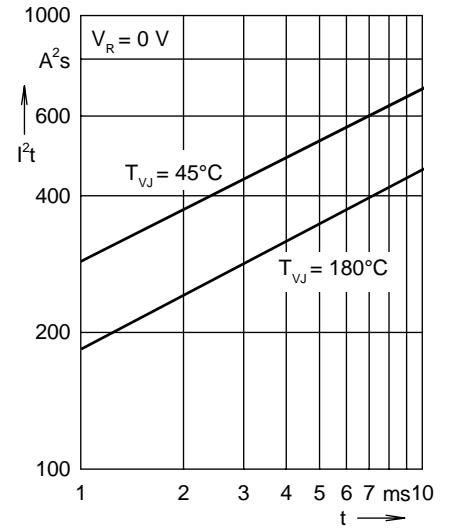


Fig. 3 I^2t versus time (1-10 ms)

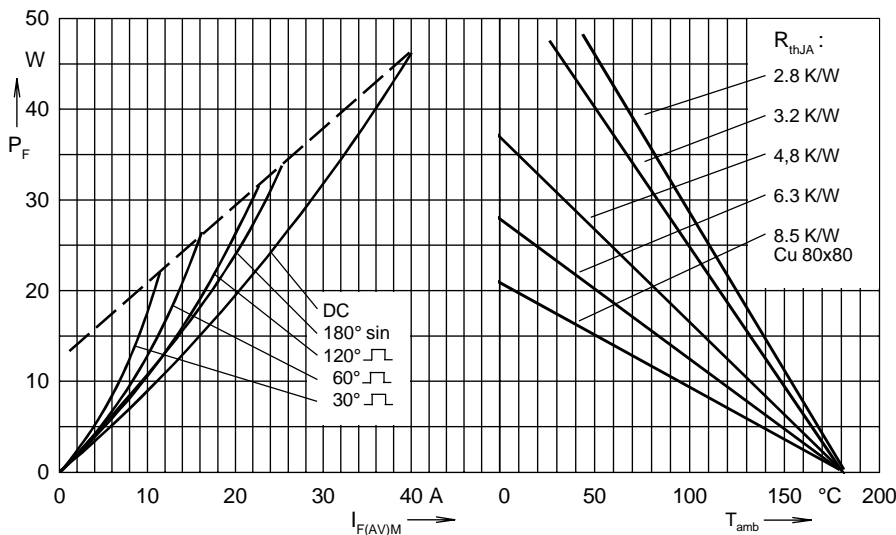


Fig. 4 Power dissipation versus forward current and ambient temperature

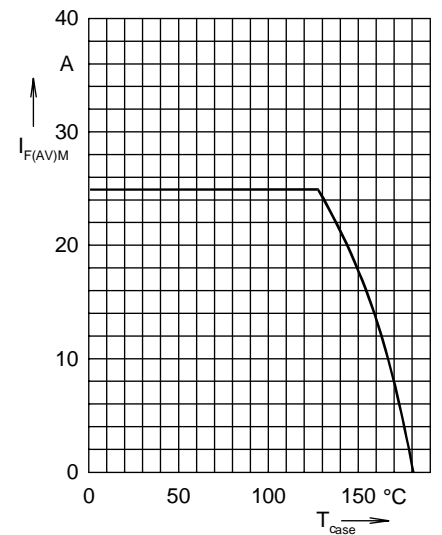


Fig. 5 Max. forward current at case temperature 180° sine

R_{thJH} for various conduction angles d:

d	R_{thJH} (K/W)
DC	2.10
180°	2.23
120°	2.33
60°	2.53
30°	2.72

Constants for Z_{thJH} calculation:

i	R_{thi} (K/W)	t_i (s)
1	0.1006	0.0021
2	0.5311	0.0881
3	0.8683	2.968
4	0.600	3.20

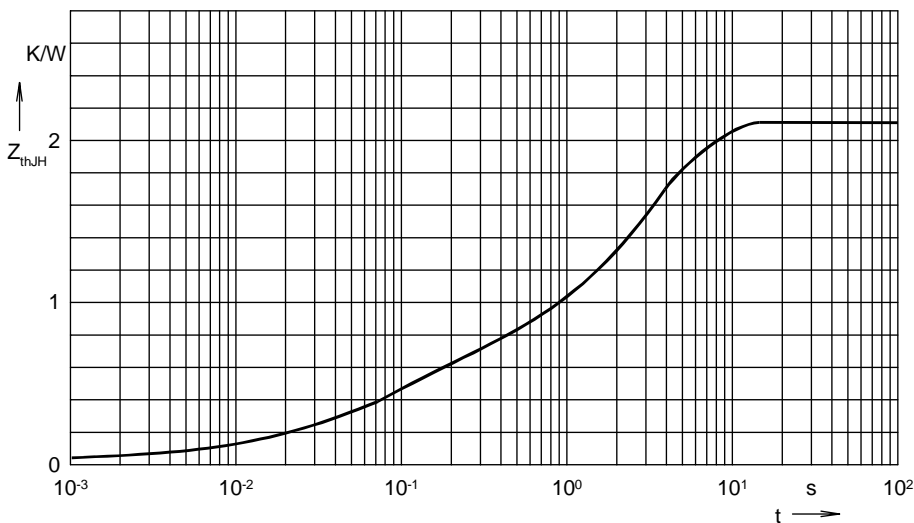


Fig. 6 Transient thermal impedance junction to heatsink